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74AHCT125

QUADRUPLE 3-STATE BUFFERS OE LOW

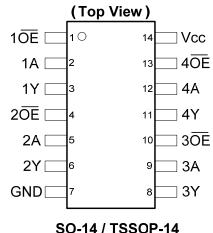
Description

The 74AHCT125 provides provides four independent buffer gates with 3-state outputs. Each buffer has a separate enable pin that if driven with a high logic level places the corresponding output in the high impedance state. The device is designed for operation with a power supply range of 4.5V to 5.5V.

Features

- Wide Supply Voltage Range from 4.5V to 5.5V
- Inputs Are TTL Voltage Level Compatible
- Outputs Sink or Source 8mA at V_{CC} = 4.5V
- CMOS Low Power Consumption
- Schmitt Trigger Action at All Inputs
- ESD Protection Exceeds JESD 22
 - 200-V Machine Model (A115-A)
 - 2000-V Human Body Model (A114-A)
 - Exceeds 1000-V Charged Device Model (C101C)
- Latch-Up Exceeds 250mA per JESD 78, Class II
- Range of Package Options SO-14 and TSSOP-14
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Pin Assignments



Applications

- General Purpose Logic
- Wide array of products such as:
 - PCs, Networking, Notebooks, Netbooks
 - Computer Peripherals, Hard Drives, CD/DVD ROM
 - TV, DVD, DVR, Set Top Box

Notes:

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

- 2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

Click here for ordering information, located at the end of datasheet

GNL



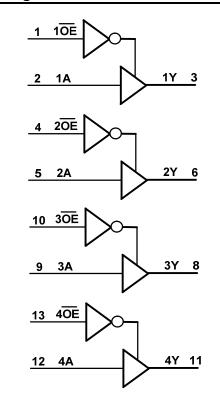
Pin Descriptions

Pin Number	Pin Name	Function
1	10E	Data Enable Input (active low)
2	1A	Data Input
3	1Y	Data Output
4	20E	Data Enable Input (active low)
5	2A	Data Input
6	2Y	Data Output
7	GND	Ground
8	3Y	Data Output
9	3A	Data Input
10	30E	Data Enable Input (active low)
11	4Y	Data Output
12	4A	Data Input
13	40E	Data Enable Input (active low)
14	V _{CC}	upply Voltage

Function Table

Inp	Inputs			
OE	Α	Y		
L	Н	Н		
L	L	L		
Н	Х	Z		

Logic Diagram



Absolute Maximum Ratings (Note 4) (@T_A = +25°C, unless otherwise specified.)

Symbol	Description	Rating	Unit
ESD HBM Human Body Model ESD Protection		2	KV
ESD CDM	Charged Device Model ESD Protection	1	KV
ESD MM	Machine Model ESD Protection	200	V
V _{CC}	Supply Voltage Range	-0.5 to +7.0	V
VI Input Voltage Range		-0.5 to +7.0	V
Input Clamp Current VI < -0.5V		-20	mA
I _{OK} Output Clamp Current V _O < 0V		-20	mA
lok	Output Clamp Current V _O > V _{CC}	20	mA
I_{O} Continuous Output Current $OV < V_{O} < V_{CC}$		+/- 25	mA
I _{CC}	Continuous Current Through V _{CC}	50	mA
I _{GND} Continuous Current Through GND		-50	mA
T _J Operating Junction Temperature		-40 to +150	°C
T _{STG} Storage Temperature		-65 to +150	°C
Ρτοτ	Total Power Dissipation	500	mW

Note: 4. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.



Recommended Operating Conditions (Note 5) (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Min	Max	Unit
V _{CC}	Supply Voltage	4.5	5.5	V
VI	Input Voltage	0	5.5	V
Vo	Output Voltage	0	Vcc	V
Δt/ΔV	Input Transition Rise or Fall Rate		20	ns/V
T _A	Operating Free-Air Temperature	-40	+125	°C

Note: 5. Unused inputs should be held at V_{CC} or Ground.

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Symphol	Devemeter	Test Conditions	N	T _A = -40°	C to +85°C	T _A = -40°C	to +125°C	Unit
Symbol	Parameter	rest conditions	Vcc	Min	Max	Min	Max	Unit
VIH	High-Level Input Voltage		4.5V to 5.5V	2.0		2.0		V
VIL	Low-Level Input Voltage		4.5V to 5.5V		0.8		0.8	V
M	High-Level	I _{OH} = -50µА	4.5V	4.4		4.4		v
Vон	Output Voltage	I _{OH} = -8mA	4.5V	3.80		3.70		v
N/	Low-Level Output	Ι _{ΟL} = 50μΑ	4.5V		0.1		0.1	v
V _{OL}	Voltage	I _{OL} = 8mA	4.5V		0.44		0.55	v
I _{OZ}	Z State Leakage Current	V _O = 0 to 5.5V	5.5V		±2.5		±10	μA
lı	Input Current	V _I = GND to 5.5V	3.6V		±1		±2	μA
Icc	Supply Current	$V_{I} = GND \text{ or } V_{CC}, I_{O} = 0$	3.6V		20		40	μA
ΔI _{CC}	Additional Supply Current	One input at V_{CC} -2.1V Other pins at V_{CC} or GND	5.5V		1.35		5	mA

Operating Characteristics

	Parameter	Test Conditions	V _{CC} = 5.5V Typ	Unit
C _{pd}	Power Dissipation Capacitance per Gate	f = 1MHz	14.8	pF
Ci	Input Capacitance	V _i = V _{CC} – or GND	4.0	pF

Switching Characteristics

Symbol	Parameter	Test Conditions	Г	_ _A = +25°	С	-40°C t	o +85°C	-40°C to	+125°C	Unit
Symbol	Falameter	Test Conditions	Min	Тур.	Max	Min	Мах	Min	Max	Unit
	Dranagation Dalay A. to V	Figure 1 C _L = 15pF	0.5	3.0	5.5	0.5	6.5	0.5	7.0	20
t _{PD}	Propagation Delay A_N to Y_N	Figure 1 C _L = 50pF	0.5	4.3	7.5	0.5	8.5	0.5	9.5	ns
	Enable Time \overline{OE}_N to Y_N	Figure 1 C _L = 15pF	0.5	6.7	10.7	0.5	11.0	0.5	11.5	
t _{EN}		Figure 1 C _L = 50pF	0.5	9.8	10.9	0.5	12.1	0.5	12.5	ns
	Disable Time \overline{OE}_N to Y_N	Figure 1 C _L = 15pF	0.5	4.8	6.8	0.5	8.0	0.5	8.5	20
t _{DIS}	Disable Time OEN to TN	Figure 1 C _L = 50pF	0.5	6.5	8.9	0.5	10.0	0.5	11.5	ns

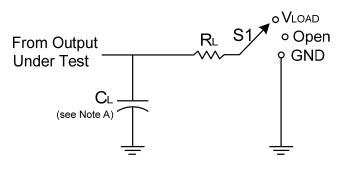


Vi

0 V

Vм

Parameter Measurement Information

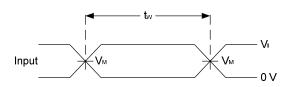


TEST	S1
t _{PLH} /t _{PHL}	Open
t _{PLZ} /t _{PZL}	Vload
t _{PHZ} /t _{PZH}	GND

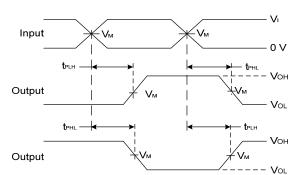
N	Inp	outs	V _M	V _M	N N	6		MA
V _{cc}	VI	t _r /t _f	Inputs	Outputs	VLOAD	CL	ĸL	VΔ
4.5V to 5.5V	3V	≤3ns	1.5V	V _{CC} /2	V _{CC}	15pF, 50pF	1K	0.3V

Output

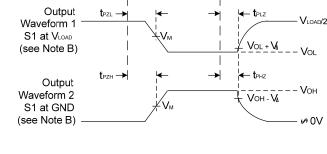
Control



Voltage Waveform Pulse Duration

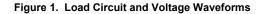






Vм

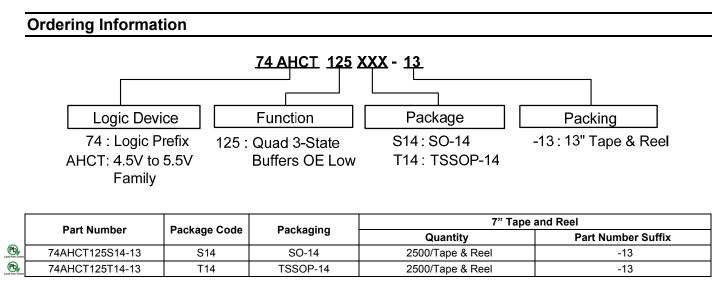
Voltage Waveform Enable and Disable Times Low and High Level Enabling



Notes: A. Includes test lead and test apparatus capacitance.

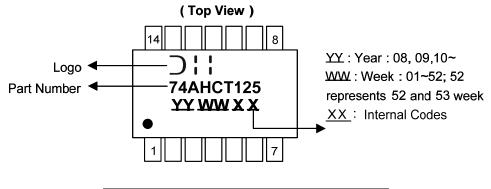
- B. All pulses are supplied at pulse repetition rate \leq 1 MHz.
- C. Inputs are measured separately one transition per measurement.
- D. t_{PLZ} and t_{PHZ} are the same as $t_{\mathsf{dis}}.$
- E. t_{PZL} and t_{PZH} are the same as t_{EN0} .
- F. t_{PLH} and t_{PHL} are the same as t_{PD}.





Marking Information

(1) SO-14, TSSOP-14



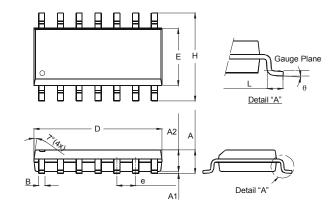
Part Number	Package
74AHCT125S14	SO-14
74AHCT125T14	TSSOP-14



Package Outline Dimensions (All dimensions in mm.)

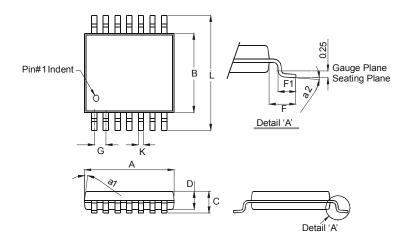
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

Package Type: SO-14



	SO-14						
Dim	Min	Max					
Α	1.47	1.73					
A1	0.10	0.25					
A2 1.45 Typ							
В	0.33	0.51					
D	8.53	8.74					
Е	3.80	3.99					
e	1.27	Тур					
Н	5.80	6.20					
L	0.38	1.27					
θ	θ 0° 8°						
All Dir	nensions	in mm					

Package Type: TSSOP-14



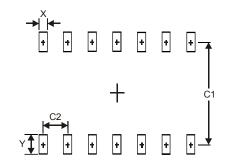
	TSSOP-	4	
Dim	Min	Max	
a1	7° (4X)		
a2	0°	8°	
Α	4.9	5.10	
В	4.30	4.50	
С		1.2	
D	0.8	1.05	
F	1.00	Тур	
F1	0.45	0.75	
G	0.65	Тур	
Κ	0.19	0.30	
L	6.40	Тур	
All Di	mension	s in mm	



Suggested Pad Layout

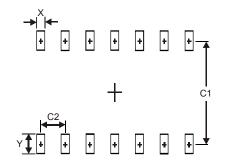
Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

Package Type: SO-14



Dimensions	Value (in mm)
Х	0.60
Y	1.50
C1	5.4
C2	1.27

Package Type: TSSOP-14



Dimensions	Value (in mm)
Х	0.45
Y	1.45
C1	5.9
C2	0.65



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